2SK1846

Silicon N-Channel Power F-MOS FET

■ Features

- Avalanche energy capacity guaranteed: EAS > 20mJ
- \bullet V_{GSS} = ± 30 V guaranteed
- \bullet High-speed switching: $t_f = 35$ ns
- No secondary breakdown

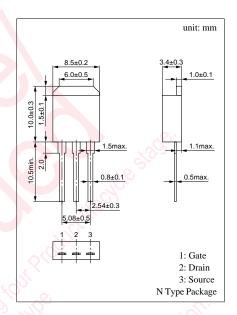
■ Applications

- Contactless relay
- Diving circuit for a solenoid
- Driving circuit for a motor
- Control equipment
- Switching power supply

■ Absolute Maximum Ratings $(T_C = 25^{\circ}C)$

Parameter		Symbol	Ratings	Unit	
Drain to Source breakdown voltage		V _{DSS}	800	V	
Gate to Source voltage		V _{GSS}	±30	V	
Drain current	DC	I_{D}	±3	A	
	Pulse	I_{DP}	±6	A	
Avalanche energy capacity		EAS*	20	mJ	
Allowable power	$T_C = 25^{\circ}C$	D	40	S W	
dissipation	Ta = 25°C	$P_{\rm D}$	1.3		
Channel temperature		T _{ch}	150	°C	
Storage temperature		T _{stg}	-55 to +150	°C	
		_			

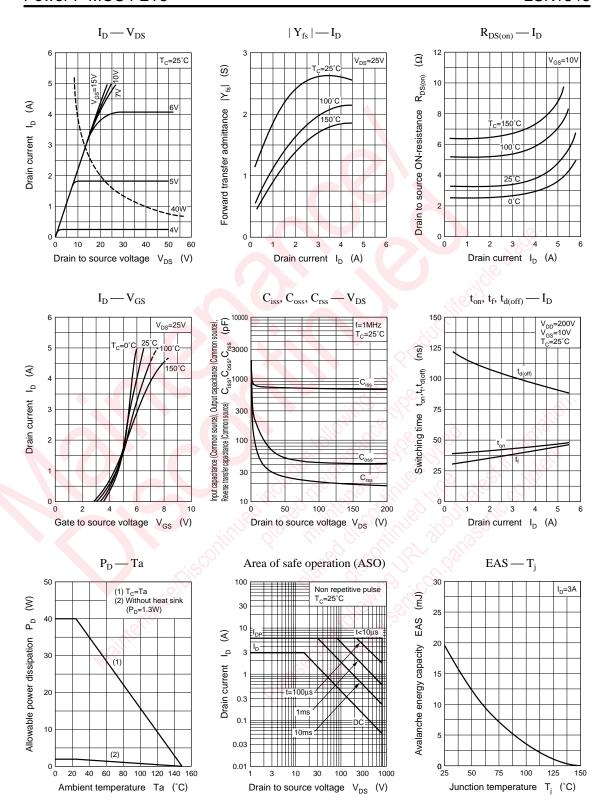
^{*} L = 4.5mH, $I_L = 3$ A, $V_{DD} = 50$ V, 1 pulse



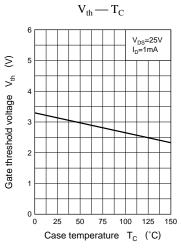
■ Electrical Characteristics (T_C = 25°C)

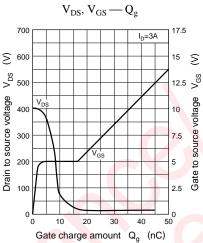
Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source cut-off current	I_{DSS}	$V_{DS} = 640V, V_{GS} = 0$	o'lli		0.1	mA
Gate to Source leakage current	I_{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0$	5		±1	μΑ
Drain to Source breakdown voltage	$V_{\rm DSS}$	$I_D = 1 \text{mA}, V_{DS} = 0$	800			V
Gate threshold voltage	V _{th}	$V_{DS} = 25V$, $I_D = 1mA$	1		5	V
Drain to Source ON-resistance	R _{DS(on)}	$V_{GS} = 10V, I_D = 2A$		3.2	4	Ω
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 25V, I_D = 2A$	1.5	2.4		S
Diode forward voltage	V _{DSF}	$I_{DR} = 3A, V_{GS} = 0$			-1.6	V
Input capacitance (Common Source)	C _{iss}			730		pF
Output capacitance (Common Source)	C _{oss}	$V_{DS} = 20V, V_{GS} = 0, f = 1MHz$		90		pF
Reverse transfer capacitance (Common Source)	C _{rss}			40		pF
Turn-on time	t _{on}	$V_{GS} = 10V, I_D = 2A$		40		ns
Fall time	t _f			35		ns
Turn-off time (delay time)	$t_{d(off)}$	$V_{DD} = 200V, R_L = 100\Omega$		105		ns
Thermal resistance between channel and case	R _{th(ch-c)}				3.125	°C/W

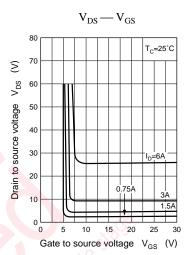
Panasonic 1



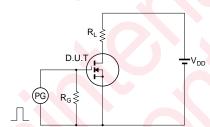
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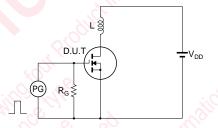




Switching measurement circuit



Avalanche energy capacity test circuit



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